

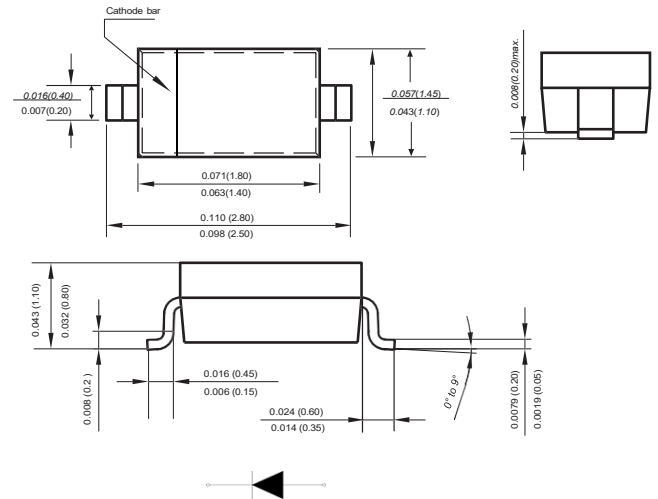
SOD-323 Plastic-Encapsulate Diodes

BZT52B2V0S-BZT52B75S ZENER DIODE

SOD-323

FEATURES

- Total power dissipation: Max. 300mW
- Wide zener reverse voltage range 2.0V to 75V.
- Small plastic package suitable for surface mounted design.
- Tolerance approximately $\pm 2\%$



Dimensions in inches and (millimeters)

Maximum Ratings($T_a=25^\circ\text{C}$ unless otherwise specified)

Characteristic	Symbol	Value	Unit
Forward Voltage at $I_F = 10\text{mA}$ (Note 2)	V_F	0.9	V
Power Dissipation(Note 1)	P_d	300	mW
Typical thermal resistance from junction to ambient(Note 1)	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Thermal resistance from junction to ambient at P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper areas pads.

2. Short duration test pulse used to minimize self-heating effect

3. $f = 1\text{kHz}$

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Type	Marking	Zener Voltage Range ⁽¹⁾				Dynamic Impedance	Reverse Current	
		V _{ZT} (at I _{ZT})			I _{ZT}	Z _{ZT} (at I _{ZT})	I _R	at V _R
		Min (V)	Nom (V)	Max (V)	(mA)	Max (Ω)	Max (μA)	(V)
BZT52B2V0S	20B	1.96	2	2.04	5	100	120	0.5
BZT52B2V2S	20C	2.16	2.2	2.24	5	100	120	0.7
BZT52B2V4S	2C1	2.35	2.4	2.45	5	100	120	1
BZT52B2V7S	2D1	2.65	2.7	2.75	5	110	120	1
BZT52B3V0S	2E1	2.94	3	3.06	5	120	50	1
BZT52B3V3S	2F1	3.23	3.3	3.37	5	130	20	1
BZT52B3V6S	2H1	3.53	3.6	3.67	5	130	10	1
BZT52B3V9S	2J1	3.82	3.9	3.98	5	130	5	1
BZT52B4V3S	2K1	4.21	4.3	4.39	5	130	5	1
BZT52B4V7S	2M1	4.61	4.7	4.79	5	130	2	1
BZT52B5V1S	2N1	5	5.1	5.20	5	130	2	1.5
BZT52B5V6S	2P1	5.49	5.6	5.71	5	80	1	2.5
BZT52B6V2S	2R1	6.08	6.2	6.32	5	50	1	3
BZT52B6V8S	2X1	6.66	6.8	6.94	5	30	0.5	3.5
BZT52B7V5S	2Y1	7.35	7.5	7.65	5	30	0.5	4
BZT52B8V2S	2Z1	8.04	8.2	8.36	5	30	0.5	5
BZT52B9V1S	2A2	8.92	9.1	9.28	5	30	0.5	6
BZT52B10S	2B2	9.8	10	10.2	5	30	0.1	7
BZT52B11S	2C2	10.78	11	11.22	5	30	0.1	8
BZT52B12S	2D2	11.76	12	12.24	5	35	0.1	9
BZT52B13S	2E2	12.74	13	13.26	5	35	0.1	10
BZT52B15S	2F2	14.7	15	15.3	5	40	0.1	11
BZT52B16S	2H2	15.68	16	16.32	5	40	0.1	12
BZT52B18S	2J2	17.64	18	18.36	5	45	0.1	13
BZT52B20S	2K2	19.6	20	20.4	5	50	0.1	15
BZT52B22S	2M2	21.56	22	22.44	5	55	0.1	17
BZT52B24S	2N2	23.52	24	24.48	5	60	0.1	19
BZT52B27S	2P2	26.46	27	27.54	2	70	0.1	21
BZT52B30S	2R2	29.4	30	30.6	2	80	0.1	23
BZT52B33S	2X2	32.34	33	33.66	2	80	0.1	25
BZT52B36S	2Y2	35.28	36	36.72	2	90	0.1	27
BZT52B39S	2Z2	38.22	39	39.78	2	100	0.1	30
BZT52B43S	2A3	42.14	43	43.86	2	130	0.1	33
BZT52B47S	2B3	46.06	47	47.94	2	150	0.1	36
BZT52B51S	2C3	49.98	51	52.02	2	180	0.1	39
BZT52B56S	2D3	54.88	56	57.12	2	200	0.1	43
BZT52B62S	2E3	60.76	62	63.24	2	215	0.1	47
BZT52B68S	2F3	66.64	68	69.36	2	240	0.1	52
BZT52B75S	2H3	73.5	75	76.5	2	265	0.1	56

(1) V_{ZT} is tested with pulses (20 ms)

Typical Characteristics

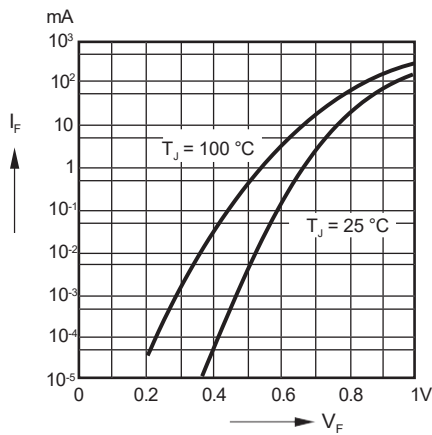


Fig. 1 - Forward characteristics

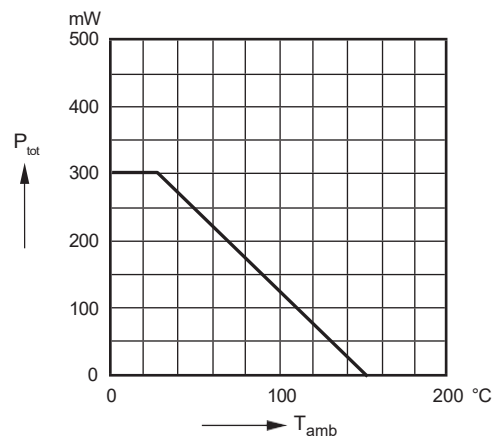


Fig. 2 - Admissible Power Dissipation vs. Ambient Temperature

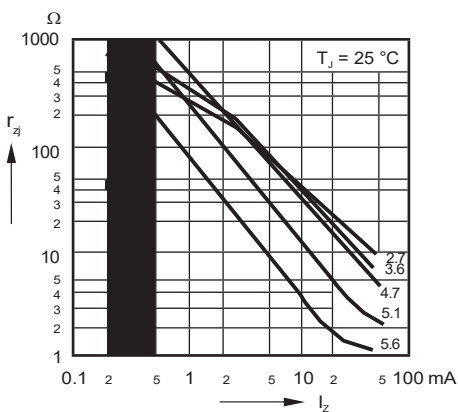


Fig. 3 - Dynamic Resistance vs. Zener Current

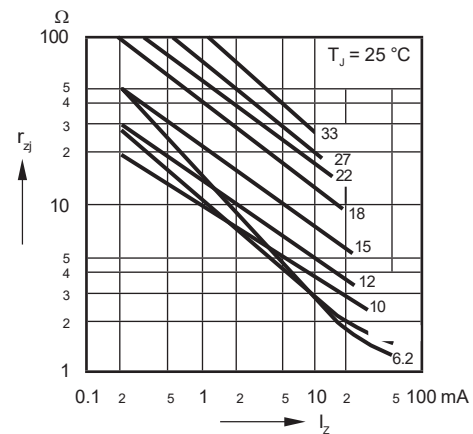


Fig. 4 - Dynamic Resistance vs. Zener Current

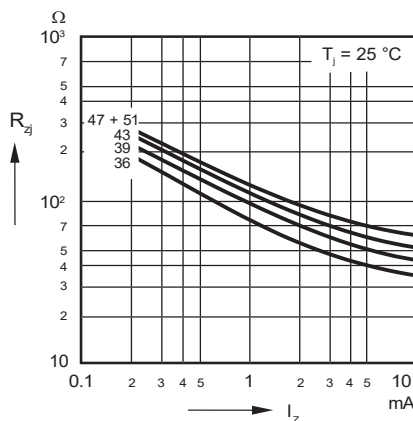


Fig. 5 - Dynamic Resistance vs. Zener Current

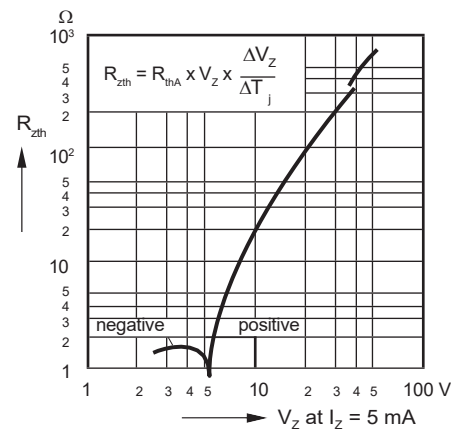


Fig. 6 - Thermal Differential Resistance vs. Zener Voltage

Typical Characteristics

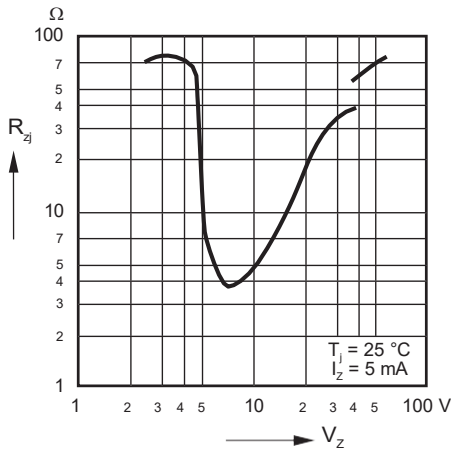


Fig. 7 - Dynamic Resistance vs. Zener Voltage



Fig. 8 - Temperature Dependence of Zener Voltage vs. Zener Voltage

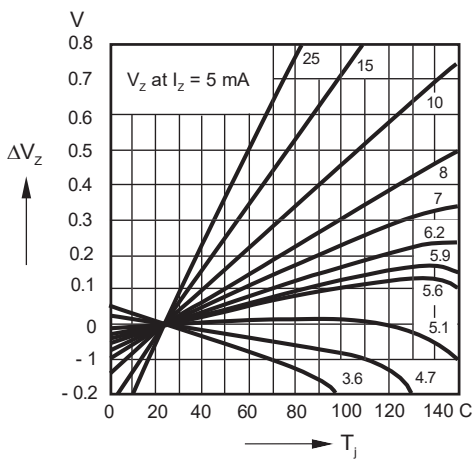


Fig. 9 - Change of Zener Voltage vs. Junction Temperature



Fig. 10 - Change of Zener Voltage vs. Junction Temperature



Fig. 11 - Temperature Dependence of Zener Voltage vs. Zener Voltage



Fig. 12 - Change of Zener Voltage from Turn-on up to the Point of Thermal Equilibrium vs. Zener Voltage

Typical Characteristics



Fig. 13 - Change of Zener Voltage from Turn-on up to the Point of Thermal Equilibrium vs. Zener Voltage

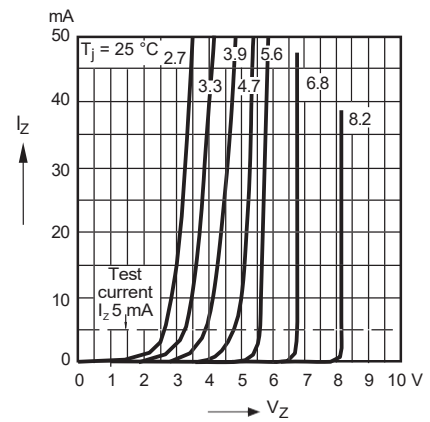


Fig. 14 - Breakdown Characteristics

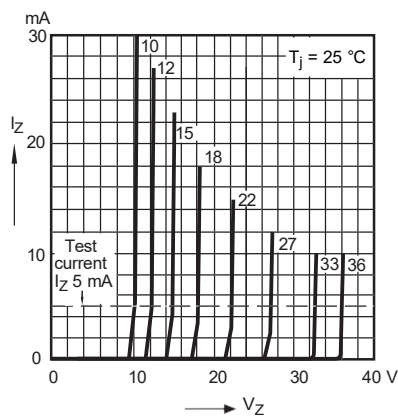


Fig. 15 - Breakdown Characteristics



Fig. 16 - Breakdown Characteristics

The curve above is for reference only.